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10/020460  
12/18/01

U.S. UTILITY Patent Application

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PATENT NUMBER and  
ISSUE DATE

APPL NUM	FILING DATE	CLASS	SUBCLASS	GAU	EXAMINER
10020460	12/18/2001	257	012	2811	Rrane

\*\*APPLICANTS: Ito Jun; Chiyo Toshiaki; Shibata Naoki; Watanabe Hiroshi; Asami Shizuyo; Asami Shinya;

\*\*CONTINUING DATA VERIFIED:

THIS APPLICATION IS A DIV OF 09/518,724 03/03/2000 U.S. Patent No. 6,426,512

\*\* FOREIGN APPLICATIONS VERIFIED:

JAPAN HEI. 11-058128 03/05/1999

JAPAN HEI. 11-060206 03/08/1999

JAPAN HEI. 11-061155 03/09/1999

PG-PUB DO NOT PUBLISH ☐

RESCIND ☐

Foreign priority claimed ☐ yes ☐ no

35 USC 119 conditions met ☐ yes ☐ no

Verified and Acknowledged Examiners's initials

ATTORNEY DOCKET NO

P 282612 T36-141808M/KOH

TITLE : Group III nitride compound semiconductor device

U.S. DEPT. OF COMM./PAT. & TM.-PTO-435L (Rev. 12-94)

NOTICE OF ALLOWANCE MAILED

Assistant Examiner

CLAIMS ALLOWED

Total Claims

Print Claim for  
O.G.

ISSUE FEE

Amount Due

Date Paid

DRAWING

Sheets Drwg.

Figs. Drwg.

Print Fig.

Primary Examiner

PREPARED FOR ISSUE

Application Examiner

☐ TERMINAL  
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